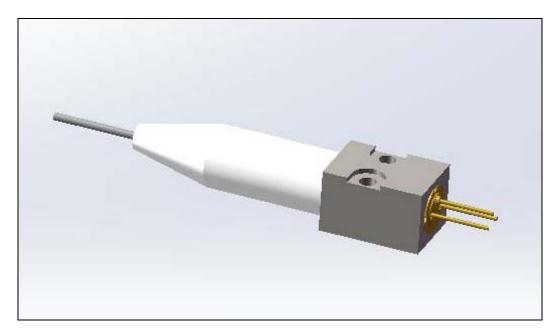
Sintec Optronics

520nm 10mW Coaxial Packaged Diode Laser STK520F03FN-0.010W



Features:

520nm wavelength 10mW output power 105µm fiber core diameter 0.22NA

Applications:

Aiming beam

Our High Power Diode Laser Modules are manufactured by adopting specialized fiber-coupling techniques, resulting in volume products with a high efficiency, stability and superior beam quality. The products are achieved by transforming the asymmetric radiation from the laser diode chip into an output fiber with small core diameter by using special micro optics. Inspecting and burn-in procedures in every aspect come to a result to guarantee each product with the reliability, stability and long lifetime.

Our research staffs are constantly improving and innovating the processing technology in the producing process, based on the professional knowledge and experience accumulated in long-terms. We are also continuously developing new products to meet customers' specific needs.

To provide high quality products with reasonable price is our always goal.

OPERATING NOTES

- Avoid eye and skin exposure to direct radiation during operation.
- ESD precautions must be taken during storage, transportation and operation.
- Short-circuit is required between pins during storage and transportation.
- Please connect pins to wires by solder instead of using socket when operation current is higher than 6A. Soldering point should be close to the root of the pins. Soldering temperature should be lower than 260 °C and time shorter than 10 second.
- Make sure the fiber output end is properly cleaned before operation of laser. Follow safety protocols to avoid injury when handling and cutting the fiber.
- Use constant current power supply to avoid surge current during operation.
- Laser diode must be used according to the specifications.
- Laser diode must work with good cooling.
- Operation temperature ranges from 15[°]C to 35[°]C.
- Storage temperature ranges from -20°C to +70°C.

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Specifications (25°C)		Symbol	Unit	STK520F03FN-0.010W		
				Minimum	Typical	Maximum
Parameter ⁽¹⁾	CW Output Power	Po	mW	10	-	-
	Threshold current	I _{th}	mA	-	60	-
	Operating current	l _{op}	mA	-	-	180
	Operating voltage	Vop	V	-	-	8
	Reverse Voltage	Vre	V	-	2	-
	Slope Efficiency	η	W/A	-	0.08	-
	Electrical-to-Optical Efficiency	PE	%	0.5	-	-
	Center wavelength	Кc	nm	510	-	530
	Spectral width(FWHM)	Δ٨	nm		3	-
	Back reflection isolation	-	dB	-	30	-
	Wavelength Shift with Temperature	-	nm/°C	-	0.2	-
Fiber Data	Buffer diameter	Dbuf	μm	-	250	-
	Cladding diameter	D _{clad}	μm	-	125	-
	Core diameter	D _{core}	μm	-	105	
	Numeric aperture	NA	NA	-	0.22	-
	Fiber length ⁽²⁾	lc	m	0.9	1	1.1
	connector	-	-	FC(APC)/SC(APC) /SMA905/ST		
	Fiber Bend Radius		mm	-	40	-
Others	ESD	-	V	-	-	500
	Storage temperature	.	°C	-20		70
	Lead Soldering Temp	Tis	°C	-	-	260
	Lead Soldering Time	Tis	sec	-	-	10
	Operating case temperature	Тор	°C	15	-	35
	Relative Humidity	-	%	15	-	75

(1) Data measured under operation output at 10mW.

(2) Other fibers available upon request.

(3) Operating temperature defined by the package case. Acceptable operating range is 15 - 35C, but performance may vary.

